GL05T to GL24T

RoHS

COMPLIANT

HALOGEN

FREE

(5-2008)

HAY	
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Low Capacitance ESD Protection Diodes for **High-Speed Data Interfaces**





2035

MARKING

(example only)



Bar = cathode marking YYY = type code (see table below)

XX = date code

DESIGN SUPPORT TOOLS



click logo to get started

± 8 kV contact discharge ± 15 kV air discharge

• ESD capability according to AEC-Q101: human body model: class H3B: > 8 kV

 IEC 61000-4-5 (lightning) see I_{PPM} below • ESD immunity acc. IEC 61000-4-2

SOT-23 package

FEATURES

- · Low capacitance for high speed data lines, **GREEN** cellular handsets, USB port protection, LAN equipment, peripherals
- e3 Sn
- AEC-Q101 qualified available
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

ORDERING INFORMATION								
	ENVIR	ONMENTAL AN	ID QUALITY CO	ODE	PACKAG	ING CODE		
PART NUMBER (EXAMPLE)	AEC-Q101 QUALIFIED	AEC-Q101 RoHS-COMPLIANT + LEAD (Pb)-FREE			3K PER 7" REEL (8 mm TAPE),	10K PER 13" REEL (8 mm TAPE),	ORDERING CODE (EXAMPLE)	
		STANDARD	GREEN	PLATED	15K/BOX = MÓQ	10K/BOX = MÔQ		
GL05T-		E		3	-08		GL05T-E3-08	
GL05T-			G	3	-08		GL05T-G3-08	
GL05T-	Н	E		3	-08		GL05T-HE3-08	
GL05T-	Н		G	3	-08		GL05T-HG3-08	
GL05T-		E		3		-18	GL05T-E3-18	
GL05T-			G	3		-18	GL05T-G3-18	
GL05T-	Н	E		3		-18	GL05T-HE3-18	
GL05T-	Н		G	3		-18	GL05T-HG3-18	

PACK	AGE DAT	Α					
DEVICE NAME	PACKAGE NAME	TYPE CODE	ENVIRONMENTAL STATUS	WEIGHT	T ROLDING COMPOUND MOISTURE FLAMMABILITY RATING SENSITIVITY LEVEL		SOLDERING CONDITIONS
GL 05T	SOT-23	L05	Standard	8.8 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	Peak temperature max. 260 °C
GL051	301-23	L06	Green	8.1 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	Peak temperature max. 260 °C
			Standard	8.8 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	Peak temperature max. 260 °C
GLIZI	301-23	L13	Green	8.1 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	Peak temperature max. 260 °C
CL 15T	SOT 22	L15	Standard	8.8 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	Peak temperature max. 260 °C
GLIST	301-23	L16	Green	8.1 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	Peak temperature max. 260 °C
CL 24T	SOT 22	L24	Standard	8.8 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	Peak temperature max. 260 °C
02241	501-25	L25	Green	8.1 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	Peak temperature max. 260 °C

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ABSOLUTE MAXIMUM RATINGS GL05T								
PARAMETER	TEST CONDITIONS		SYMBOL	VALUE	UNIT			
Peak pulse current	8/20 µs	$\operatorname{Pin} 1 2 (\operatorname{pin} 2 \operatorname{p} \circ)$	I _{PPM}	25	А			
Peak pulse power	8/20 µs waveform	Fin 1-2 (pin 3 n.c.)	P _{PP}	300	W			
	Contact discharge acc. IEC 61000-4-2; 10 pulses		V _{ESD}	± 8	kV			
	Air discharge acc. IEC 61000-4-2; 10 pulses			± 15	kV			
Blocking voltage	I _B = 1 μΑ	Pin 2-1 or pin 2-3	VB	70	V			
Operating temperature	Junction temperatu	ire	TJ	-55 to +150	°C			
Storage temperature			T _{STG}	-55 to +150	°C			

ABSOLUTE MAXIMUM RATINGS GL12T							
PARAMETER	TEST CONDITIONS		SYMBOL	VALUE	UNIT		
Peak pulse current	8/20 µs	$\operatorname{Pin} 1.2(\operatorname{pin} 3.n.c)$	I _{PPM}	12	А		
Peak pulse power	8/20 µs waveform	Fin 1-2 (pin 3 n.c.)	P _{PP}	300	W		
	Contact discharge acc. IEC 61000-4-2; 10 pulses		M	± 8	kV		
ESD minuting	Air discharge acc. IEC 61000-4-2; 10 pulses		VESD	± 15	kV		
Blocking voltage	I _B = 1 μΑ	Pin 2-1 or pin 2-3	VB	70	V		
Operating temperature	Junction temperature		TJ	-55 to +150	°C		
Storage temperature			T _{STG}	-55 to +150	°C		

ABSOLUTE MAXIMUM RATINGS GL15T							
PARAMETER	TEST CONDITIONS		SYMBOL	VALUE	UNIT		
Peak pulse current	8/20 µs	$\operatorname{Pin} 1 2 (\operatorname{pin} 2 \operatorname{p} c)$	I _{PPM}	10	A		
Peak pulse power	8/20 µs waveform	Fin 1-2 (pin 3 n.c.)	P _{PP}	300	W		
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses		V	± 8	kV		
	Air discharge acc. IEC 61000-4-2; 10 pulses		V ESD	± 15	kV		
Blocking voltage	I _B = 1 μΑ	Pin 2-1 or pin 2-3	VB	70	V		
Operating temperature	Junction temperature		TJ	-55 to +150	°C		
Storage temperature			T _{STG}	-55 to +150	°C		

ABSOLUTE MAXIMUM RATINGS GL24T								
PARAMETER	TEST CONDITIONS		SYMBOL	VALUE	UNIT			
Peak pulse current	8/20 µs	$\operatorname{Pin} 1 2 (\operatorname{pin} 2 \operatorname{p} 2)$	I _{PPM}	5	А			
Peak pulse power	8/20 µs waveform	Fin 1-2 (pin 3 n.c.)	P _{PP}	300	W			
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses			± 8	kV			
	Air discharge acc. IEC 61000-4-2; 10 pulses		▼ESD	± 15	kV			
Blocking voltage	I _B = 1 μΑ	Pin 2-1 or pin 2-3	VB	70	V			
Operating temperature	Junction temperature		TJ	-55 to +150	°C			
Storage temperature			T _{STG}	-55 to +150	°C			

The GLxxT contains an avalanche diode (pin 3-1) and a switching diode (pin 3-2). With pin 1 connected to the signal or data line and pin 2 connected to ground both diodes are in series (pin 3 remains unconnected). The big and robust avalanche diode, driven in reverse direction, provides the working range V_{RWM} of 5 V, 12 V, 15 V or 24 V. Due to its size the capacitance of the avalanche diode is in the range of typ. 260 pF (GL05T) and 65 pF (GL24T). The small switching diode in series has a low capacitance of just 2.5 pF (typ.). As both diodes are in series (with pin 3 not connected) the total capacitance of both diodes measured between pin 1 and 2 is as low as the capacitance of the switching diode.

Before the GLxxT can provide this low capacitance the big capacitance of the avalanche diode has to be charged up with the first signal or data pulses. This is usually no problem for digital signals like USB or other data ports.

With the GLxxT a signal or data line can be protected against positive transients only. For negative transients another GLxxT can be used to provide a back path for the negative transients as well.

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ground

Uni Unidirectional clamping performance for positive transients only.

ground



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BiAs Bidirectional and Asymmetrical clamping performance for positive and negative transients.

ELECTRICAL CHARACTERISTICS GL05T (T _{amb} = 25 °C unless otherwise specified) pin 1 to pin 2; pin 3 not connected									
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT			
Protection paths	Number of lines which can be protected	N _{channel}	-	-	1	lines			
Reverse stand-off voltage	Max. reverse working voltage	V _{RWM}	-	-	5	V			
Reverse voltage	at I _R = 20 μA	V _R	5	-	-	V			
Reverse current	at V _R = 5 V	I _R	-	-	20	μA			
Reverse breakdown voltage	at I _R = 1 mA	V _{BR}	6.9	7.5	8.0	V			
Povorso clamping voltago	at I _{PP} = 1 A	V.	-	-	9.8	V			
neverse clamping voltage	at I _{PP} = 5 A	vc	-	-	11	V			
Capacitance	at $V_R = 0 V$; f = 1 MHz	CD	-	2.5	5	pF			

ELECTRICAL CHARACTERISTICS GL12T (T_{amb} = 25 °C unless otherwise specified) pin 1 to pin 2: pin 3 not connected

P						
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Protection paths	Number of lines which can be protected	N _{channel}	-	-	1	lines
Reverse stand-off voltage	Max. reverse working voltage	V _{RWM}	-	-	12	V
Reverse voltage	at I _R = 1 μA	V _R	12	-	-	V
Reverse current	at V _R = 12 V	I _R	-	-	1	μA
Reverse breakdown voltage	at I _R = 1 mA	V _{BR}	13.3	14.3	17.2	V
Povorso clamping voltago	at I _{PP} = 1 A	V.	-	-	19	V
neverse clamping voltage	at I _{PP} = 5 A	۷C	-	TYP. MAX. - 1 - 12 - - - 1 14.3 17.2 - 19 - 24 2.5 5	V	
Capacitance	at $V_R = 0 V$; f = 1 MHz	CD	-	2.5	5	pF

ELECTRICAL CHARACTERISTICS GL15T (T _{amb} = 25 °C unless otherwise specified) pin 1 to pin 2; pin 3 not connected									
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT			
Protection paths	Number of lines which can be protected	N _{channel}	-	-	1	lines			
Reverse stand-off voltage	Max. reverse working voltage	V _{RWM}	-	-	15	V			
Reverse voltage	at I _R = 1 μA	V _R	15	-	-	V			
Reverse current	at V _R = 15 V	I _R	-	-	1	μA			
Reverse breakdown voltage	at I _R = 1 mA	V _{BR}	16.7	17.7	22	V			
Poverse elemping veltage	at I _{PP} = 1 A	V.	-	-	24	V			
neverse clamping voltage	at I _{PP} = 5 A	vc	-	-	33	V			
Capacitance	at $V_R = 0 V$; f = 1 MHz	CD	-	2.5	5	pF			



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ELECTRICAL CHARACTERISTICS GL24T (T _{amb} = 25 °C unless otherwise specified) pin 1 to pin 2; pin 3 not connected									
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT			
Protection paths	Number of lines which can be protected	N _{channel}	-	-	1	lines			
Reverse stand-off voltage	Max. reverse working voltage	V _{RWM}	-	-	24	V			
Reverse voltage	at I _R = 1 μA	V _R	24	-	-	V			
Reverse current	at V _R = 24 V	I _R	-	-	1	μA			
Reverse breakdown voltage	at I _R = 1 mA	V _{BR}	26.7	28.2	33	V			
Poverse elemping veltage	at I _{PP} = 1 A	V.	-	-	43	V			
neverse clamping voltage	at I _{PP} = 5 A	VC	-	-	55	V			
Capacitance	at $V_R = 0 V$; f = 1 MHz	CD	-	2.5	5	pF			



Fig. 1 - Typical Forward Current I_{F} vs. Forward Voltage V_{F}



Fig. 2 - Typical Forward Current I_F vs. Forward Voltage V_F



Fig. 3 - Typical Reverse Voltage V_{R} vs. Reverse Current I_{R}

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PACKAGE DIMENSIONS in millimeters (inches): SOT-23







Foot print recommendation:



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Orientation in carrier tape SOT-23 S8-V-3929 01-006 (4)

SOT-23 S8-V-3929.01-006 (4) 04.02.2010 22607 Unreeling direction





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